

BAT54WS DIODE

SCHOTTKY BARRIER DIODES

DESCRIPTION

Planar Schottky barrier diodes are encapsulated in the SOD-323 small plastic SMD package. Single diodes and dual diodes with different pin configuration are available.

FEATURES

- * Low forward voltage
- * Guard ring protected
- * Small plastic SMD package
- **SYMBOL**

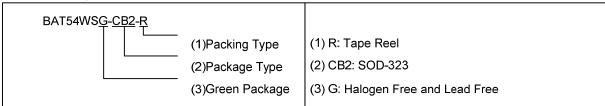




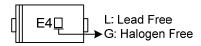
ORDERING INFORMATION

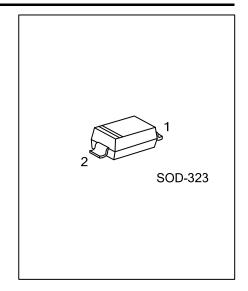
Ordering Number		Dookogo	Pin Assignment		Dooking	
Lead Free	Halogen Free	Package	1	2	Packing	
BAT54WSL-CB2-R	BAT54WSG-CB2-R	SOD-323	Α	K	Tape Reel	

Note: Pin Assignment: A: Anode K: Cathode



MARKING





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■ ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT		
PER DIODE					
Continuous Reverse Voltage	V_R	30	V		
Continuous Forward Current	l _F	200	mA		
Repetitive Peak Forward Current (t _P <1s, δ≤0.5)	I _{FRM}	300	mA		
Non-repetitive Peak Forward Current (t _P <10ms)	I _{FSM}	600	mA		
Junction Temperature	T_J	+125	°C		
Storage Temperature	T _{STG}	-60 ~ +150	°C		
PER DEVICE					
Power Dissipation (T _A ≤25°C)	P_{D}	230	mW		

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	244	°C/W

■ ELECTRICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Forward Voltage (See Fig.1)	V _F	$I_F = 0.1 \text{mA}$			240	mV
		I _F = 1mA			320	mV
		I _F = 10mA			400	mV
		I _F = 30mA			500	mV
		I _F = 100mA			800	mV
Reverse Current (See Fig.2)	I_R	V _R = 25V			2	μA
	t _{rr}	When switched from I _F =10mA				
Reverse Recovery Time (see Fig.4)		to I_R = 10mA, R_L = 100 Ω			5	ns
		measured at I _R = 1mA				
Diode Capacitance (see Fig.3)	C_D	$f = 1 \text{ MHz}, V_R = 1V;$			10	pF

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■ TYPICAL CHARACTERISTICS

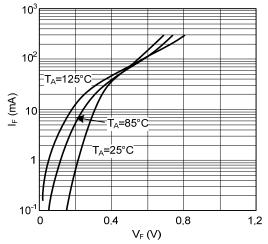


Fig.1 Forward current as a function of forward voltage; typical values.

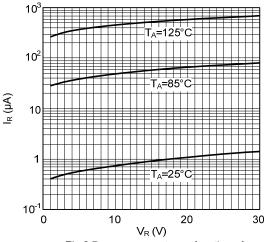


Fig.2 Reverse current as a function of reverse voltage; typical values.

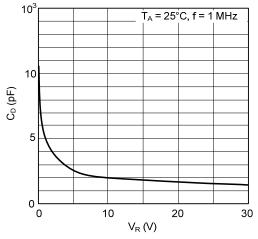


Fig.3 Diode capacitance as a function of reverse voltage; typical values.

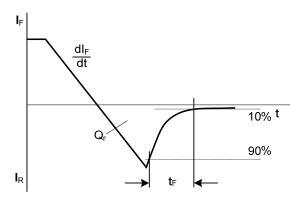


Fig.4 Reverse recovery definitions

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